

# IEUVI MASK TWG

## Sunday February 22, 2009



1:00 PM – 1:10 PM	Introduction and Greetings	<i>K. Orvek, SEMATECH</i>
1:10 PM – 2:00 PM	<b>SEMI Standards Updates</b> <ul style="list-style-type: none"><li>• 4466B Draft for Carrier – Voting End February 18</li><li>• P40 Slightly Revised Draft for Voting April 13</li><li>• P37 New Draft Version – Specifications Moving to ITRS</li></ul>	<i>L. He, Intel</i> <i>J. Zimmerman, ASML</i> <i>K. Orvek, SEMATECH</i>
2:00 PM – 2:50 PM	ITRS Roadmap, Specifications for EUVL Masks 2010-2012	
2:50 PM – 3:10 PM	Break	
3:10 PM – 3:20 PM	Review Mask Infrastructure Readiness Survey Results	<i>K. Orvek, SEMATECH</i>
3:20 PM – 4:50 PM	<b>Focus Topics: Mask Defect Density</b> <ul style="list-style-type: none"><li>• Blank Defects</li><li>• Real-World Printing of EUV Mask Defects</li><li>• Covering Defects – Fiducial Status</li></ul>	<i>H. Yun, SEMATECH</i> <i>O. Wood, AMD</i> <i>S. Huh, SEMATECH</i>
4:50 PM – 5:00 PM	<b>Wrap Up and Plans for Next TWG Meeting</b>	<i>K. Orvek, SEMATECH</i>
5:00 PM – 6:00 PM	<b>Extra Session: In-Depth Discussion of Fiducials</b>	<i>S. Huh, SEMATECH</i> <i>P. Yang, Intel</i>

## IEUVI Mask TWG -> two TWG's



- Masks are the 2<sup>nd</sup> highest issue facing EUVL (source #1)
- Sources limit throughput, but masks could end up preventing any yield
  - ! Masks are more of a 'Showstopper'
- There are too many issues and activities related to masks to cover in one 4-hour TWG.
- SEMATECH is proposing to IEUVI Board to have two TWG's focusing on mask issues:
  - EUV Mask Build
  - EUV Mask Use

# International EUV Initiative



**IEUVI Source TWG**

~~**IEUVI Optics TWG**~~



**IEUVI Mask Build TWG**

**IEUVI Resist TWG**

**IEUVI Mask Usage TWG**

**International EUV Initiative Executive Board**

*<http://www.ieuvi.org>*

*Executive Chair: Paolo Gargini*

- *Regular coordination meetings*
- *Technical Working Groups*
- *Benchmarking data exchange*
- *Co-sponsorship of workshops*

# Focus of the two Mask TWGs



## ➤ EUV Mask Build TWG:

- Infrastructure items directly related to building masks
  - Tools – inspection, writing, cleaning, repair
  - Materials – substrate, films
  - Defects
  - SEMI standards for substrates, blanks, masks

## ➤ EUV Mask Use TWG:

- Issues more directly related to using masks
  - CTE of substrate and mask build/use temperatures
  - Flatness compensation
  - Incident angle of exposure light
  - Defect masking thru pattern placement (fiducials)
  - Carriers
  - Potential Pellicles
  - ITRS roadmap



## **Next meeting of IEUVI Mask TWG(s)**

- **During SEMATECH'S EUV Symposium**
  - **October**
  - **Prague, Czech Republic**

**And now, the fun continues with an extended session on Fiducials**